

P_rinciples and E_lements

of

POWER ELECTRONICS

Devices, Drivers, Applications, and Passive Components

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Published by *Barry W Williams*

ISBN 978-0-9553384-0-3

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2006

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Naturally Commutating AC to DC Converters - Controlled Rectifiers

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PREFACE

The book is in four parts.

Part 1 covers power semiconductor switching devices, their static and dynamic electrical and thermal characteristics and properties. Part 2 describes device driving and protection, while Part 3 presents a number of generic applications. The final part, Part 4, introduces capacitors, magnetic components, resistors, and dc relays and their characteristics relevant to power electronic applications.

- 1 Basic Semiconductor Physics and Technology
- 2 The pn Junction
- 3 Power Switching Devices and their Static Electrical Characteristics
- 4 Electrical Ratings and Characteristics of Power Semiconductor Switching Devices
- 5 Cooling of Power Switching Semiconductor Devices
- 6 Load, Switch, and Commutation Considerations
- 7 Driving Transistors and Thyristors
- 8 Protecting Diodes, Transistors, and Thyristors
- 9 Switching-aid Circuits with Energy Recovery
- 10 Series and Parallel Device Operation, Protection, and Interference
- 11 Naturally Commutating AC to DC Converters – Uncontrolled Rectifiers
- 12 Naturally Commutating AC to DC Converters – Controlled Rectifiers
- 13 AC Voltage Regulators
- 14 DC Choppers
- 15 DC to AC Inverters – Switched Mode
- 16 DC to AC Inverters – Resonant Mode
- 17 DC to DC Converters - Switched-mode
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- 19 HV Direct-Current Transmission
- 20 FACTS Devices and Custom Controllers
- 21 Inverter Grid Connection for Embedded Generation
- 22 Energy Sources and Storage: Primary Sources
- 23 Energy Sources and Storage: Secondary Sources
- 24 Capacitors
- 25 Resistors
- 26 Soft Magnetic Materials: Inductors and Transformers
- 27 Hard Magnetic Materials: Permanent Magnets
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The 162 non-trivial worked examples cover the key issues in power electronics.

BWW
March 2012